

SL2101 Synthesized Broadband Converter with Programmable Power

Data Sheet

Features

- Single chip synthesized broadband solution
- Configurable as both up converter and downconverter requirements in double conversion tuner applications
- Incorporates 8 programmable mixer power settings
- Compatible with digital and analogue system requirements
- CSO -65 dBc, CTB -68 dBc (typical)
- Extremely low phase noise balanced local oscillator, with very low fundamental and harmonic radiation
- PLL frequency synthesizer designed for high comparison frequencies and low phase noise
- Buffered crystal output for pipelining system reference frequency
- I²C Controlled

Applications

- Double conversion tuners
- Digital Terrestrial tuners
- Cable telephony
- Cable Modems
- MATV

August 2004

Ordering Information

SL2101C/KG/NP1P SSOP Tubes SL2101C/KG/NP1Q SSOP Tape & Reel SL2101C/KG/NP2P SSOP* Tubes SL2101C/KG/NP2Q SSOP* Tape & Reel SL2101C/KG/LH2N MLP* Tape & Reel * Pb free All codes baked and drypacked

-40°C to +85°C

Description

The SL2101 is a fully integrated single chip broadband mixer oscillator with low phase noise PLL frequency synthesizer. It is intended for use in double conversion tuners as both the up and down converter and is compatible with HIIF frequencies up to 1.4 GHz and all standard tuner IF output frequencies. It also contains a programmable power facility for use in systems where power consumption is important.

The device contains all elements necessary, with the exception of local oscillator tuning network, loop filter and crystal reference to produce a complete synthesized block converter, compatible with digital and analogue requirements.

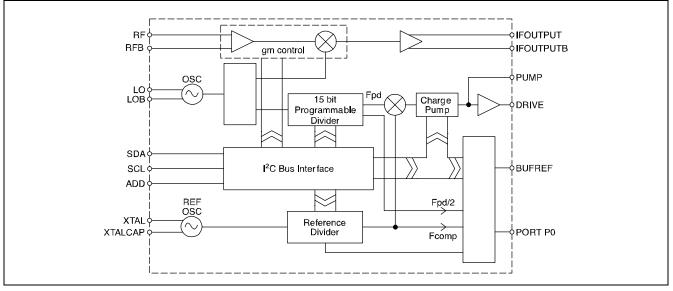
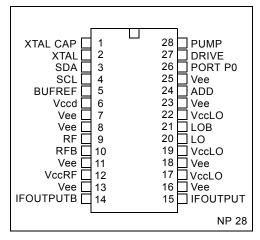


Figure 1 - Functional Block Diagram





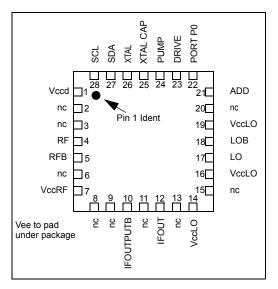


Figure 3 - Pin Diagram MLP Package

Quick Reference Data

All data applies at maximum power setting with the following conditions unless otherwise stated;

a) nominal loads as follows;

1220 MHz output load as in Figure 4

44 MHz output load as in Figure 5

b) input signal per carrier of 63 $dB\mu V$

| Characteristic | | Units |
|--|-----------------------|------------------|
| RF input operating range | 50-1400 | MHz |
| Input noise figure, SSB, 50-860 MHz 860-1400 | 6.5 - 8.5 8.5 - 12 | dB dB |
| Conversion gain | 12 | dB |
| CTB (fully loaded matrix) | -68 | dBc |
| CSO (fully loaded matrix) | -65 | dBc |
| P1 dB input referred | 110 | dBμV |
| Local oscillator phase noise as upconverter SSB @ 10 kHz offset SSB @ 100 kHz offset | -90 -112 | dBc/Hz dBc/Hz |
| Local oscillator phase noise as downconverter SSB @ 10 kHz offset SSB @ 100 kHz offset | -93 -115 | dBc/Hz dBc/Hz |
| Local oscillator phase noise floor | -136 | dBc/Hz |
| PLL spurs on converted output with input @ 60 dB μ V | <-70 | dBc |
| PLL maximum comparison frequency | 4 | MHz |
| PLL phase noise at phase detector | -152 | dBc/Hz |

*dBm assumes a 75 Ω characteristic impedance, and 0 dBm = 109 dB μV

Functional Description

The SL2101 is a broadband wide dynamic range mixer oscillator with on-board I²C bus controlled PLL frequency synthesizer, optimized for application in double conversion tuner systems as both the up and down converter. It also has application in any system where a wide dynamic range broadband synthesized frequency converter is required.

The SL2101 is a single chip solution containing all necessary active circuitry and simply requires an external tuneable resonant network for the local oscillator sustaining network. The pin assignment is contained in Figures 2 and 3 for the SSOP and MLP packages and the block diagram in Figure 1.

The device also contains a programmable facility to adjust the power in the lna/mixer so allowing power to be traded against intermodulation performance for power critical applications, such as telephony modems.

Converter Section

In normal application the RF input is interfaced through appropriate impedance matching and an AGC front end to the device input. The RF input preamplifier of the device is designed for low noise figure, within the operating region of 50 to 1400 MHz and for high intermodulation distortion intercept so offering good signal to noise plus composite distortion spurious performance when loaded with a multi carrier system. The preamplifier also provides gain to the mixer section and back isolation from the local oscillator section.

The lna/mixer current and hence signal handling and device power consumption are programmable through the I^2C bus as tabulated in Figure 7.

The typical RF input impedance and matching network for broadband upconversion are contained in Figures 8 and 9 respectively and for narrow band downconversion in Figures 10 and 11 respectively. The input referred two tone intermodulation test condition spectrum at maximum power setting is shown in Figure 12. The typical input NF and gain versus frequency and NF specification limits, over selectable power settings are contained in Figures 13, 14 and 15 respectively.

The output of the preamplifier is fed to the mixer section which is optimized for low radiation application. In this stage the RF signal is mixed with the local oscillator frequency, which is generated by the on-board oscillator. The oscillator block uses an external tuneable network and is optimized for low phase noise. The typical oscillator application as an upconverter is shown in Figure 16 and the typical phase noise performance in Figure 17. The typical oscillator application as a downconverter is shown in Figure 18, and the phase noise performance in Figure 19. This oscillator block interfaces direct with the internal PLL to allow for frequency synthesis of the local oscillator.

Finally the output of the mixer provides an open collector differential output drive. The device allows for selection of an IF in the range 30-1400 MHz so covering standard HIIFs between 1 and 1.4 GHz and all conventional tuner output IFs. When used as a broadband upconverter to a HIIF the output should be differentially loaded, for example with a differential SAW filter, to maximize intermodulation performance. A nominal load in maximum power setting is shown in Figure 4, which will typically be terminated with a differential 200 load. When used as a narrowband downconverter the output should be differentially loaded with a discrete differential to single ended converter as in Figure 5, shown tuned to 44 MHz IF. Alternatively loading can be direct into a differential input amplifier or SAWF, in which case external loads to Vcc will be required. An example load for 44 MHz application with a gain of 16 dB is contained in Figure 6. The NF and gain with recommended load versus power setting are contained in Figure 20.

The typical IF output impedance as upconverter and downconverter are contained in Figures 21 and 22 respectively.

In all applications care should be taken to achieve symmetric balance to the IF outputs to maximize intermodulation performance.

The typical key performance data at 5V Vcc and 25 deg C ambient are shown in the section 'Quick Reference Data'.

PLL Frequency Synthesizer

The PLL frequency synthesizer section contains all the elements necessary, with the exception of a reference frequency source and loop filter to control the oscillator, so forming a complete PLL frequency synthesized source. The device allows for operation with a high comparison frequency and is fabricated in high speed logic, which enables the generation of a loop with good phase noise performance.

The LO signal from the oscillator drives an internal preamplifier, which provides gain and reverse isolation from the divider signals. The output of the preamplifier interfaces direct with the 15-bit fully programmable divider. The programmable divider is of MN+A architecture, where the dual modulus prescaler is 16/17, the A counter is 4-bits, and the M counter is 11 bits.

The output of the programmable divider is fed to the phase comparator where it is compared in both phase and frequency domain with the comparison frequency. This frequency is derived either from the on-board crystal controlled oscillator or from an external reference source. In both cases the reference frequency is divided down to

the comparison frequency by the reference divider which is programmable into 1 of 29 ratios as detailed in figure 23. Typical applications for the crystal oscillator are contained in Figure 24 and Figure 25. Figure 25 is used when driving a second SL2101 as a downconverter.

The output of the phase detector feeds a charge pump and loop amplifier, which when used with an external loop filter and high voltage transistor, integrates the current pulses into the varactor line voltage, used for controlling the oscillator.

The programmable divider output Fpd divided by two and the reference divider output Fcomp can be switched to port P0 by programming the device into test mode. The test modes are described in Figure 26.

The crystal reference frequency can be switched to BUFREF output by bit RE as described in Figure 27. The BUFREF output is not available on the MLP package.

Programming

The SL2101 is controlled by an I²C data bus and is compatible with both standard and fast mode formats.

Data and Clock are fed in on the SDA and SCL lines respectively as defined by I²C bus format. The device can either accept data (write mode), or send data (read mode). The LSB of the address byte (R/W) sets the device into write mode if it is low, and read mode if it is high. Tables 1 and 2 in Figure 28 illustrate the format of the data. The device can be programmed to respond to several addresses, which enables the use of more than one device in an I²C bus system. Figure 28, Table 3 shows how the address is selected by applying a voltage to the 'ADD' input. When the device receives a valid address byte, it pulls the SDA line low during the acknowledge period, and during following acknowledge periods after further data bytes are received. When the device is programmed into read mode, the controller accepting the data must pull the SDA line low during all status byte acknowledge periods to read another status byte. If the controller fails to pull the SDA line low during this period, the device generates an internal STOP condition, which inhibits further reading.

Write Mode

With reference to Figure 28, Table 1, bytes 2 and 3 contain frequency information bits 2^{14} - 2^{0} inclusive.

Byte 4 controls the synthesizer reference divider ratio, see Figure 23 and the charge pump setting, see Figure 29. Byte 5 controls the test modes, see Figure 26, the buffered crystal reference output select RE, see Figure 27, the power setting, see Figure 7 and the output port P0.

After reception and acknowledgement of a correct address (byte 1), the first bit of the following byte determines whether the byte is interpreted as a byte 2 or 4, a logic '0' indicating byte 2, and a logic '1' indicating byte 4. Having interpreted this byte as either byte 2 or 4 the following data byte will be interpreted as byte 3 or 5 respectively. Having received two complete data bytes, additional data bytes can be entered, where byte interpretation follows the same procedure, without re-addressing the device. This procedure continues until a STOP condition is received. The STOP condition can be generated after any data byte, if however it occurs during a byte transmission, the previous byte data is retained. To facilitate smooth fine tuning, the frequency data bytes are only accepted by the device after all 15 bits of frequency data have been received, or after the generation of a STOP condition.

Read Mode

When the device is in read mode, the status byte read from the device takes the form shown in Figure 28, Table 2.

Bit 1 (POR) is the power-on reset indicator, and this is set to a logic '1' if the Vcc supply to the device has dropped below 3V (at 25° C), e.g., when the device is initially turned ON. The POR is reset to '0' when the read sequence is terminated by a STOP command. When POR is set high this indicates that the programmed information may have been corrupted and the device reset to the power up condition.

Bit 2 (FL) indicates whether the synthesizer is phase locked, a logic '1' is present if the device is locked, and a logic '0' if the device is unlocked.

Programmable Features

| Synthesizer programmable divider | Function as described above |
|---|--|
| Reference programmable divider | Function as described above. |
| Charge pump current | The charge pump current can be programmed by bits C1 & C0 within data byte 4, as defined in Figure 29. |
| Power setting | The device power and hence signal handling can be programmed by bits I2 - I0 within data byte 5, as defined in Figure 7. |
| | In all power settings the synthesizer remains enabled to facilitate rapid PLL lock reacquisition |
| Test mode | The test modes are defined by bits T2 - T0 as described in Figure 26. |
| General purpose ports, P0 | The general purpose port can be programmed by bits P0; |
| | Logic '1' = on |
| | Logic '0' = off (high impedance) - this is the default state at device power on |
| Buffered crystal reference output BLIEREI | EThe buffered crystal reference frequency can be switched to the |

Buffered crystal reference output, BUFREFThe buffered crystal reference frequency can be switched to the BUFREF output by bit RE as described in Figure 27. The BUFREF output defaults to the 'ON' condition at device power up. This output is only available on the SSOP package.

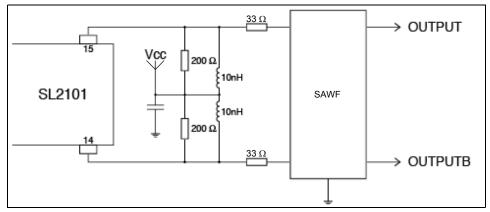
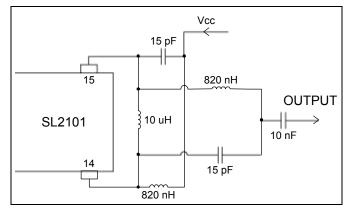
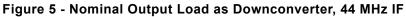


Figure 4 - Nominal Output Load as Upconverter into Differential SAWF





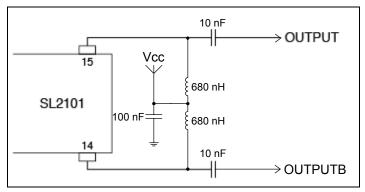


Figure 6 - Output Load as Downconverter to a Differential Amplifier

| 10 | 12 11 | 10 | Supply Cu | rrent in mA | | |
|----|-------|----|-----------|-------------|--|--|
| 12 | | 10 | Тур. | Max. | | |
| 0 | 0 | 0 | 90* | 120 | | |
| 0 | 0 | 1 | 67 | 89 | | |
| 0 | 1 | 0 | 56 | 75 | | |
| 0 | 1 | 1 | 51 | 68 | | |
| 1 | 0 | 0 | 82 | 109 | | |
| 1 | 0 | 1 | 59 | 78 | | |
| 1 | 1 | 0 | 48 | 64 | | |
| 1 | 1 | 1 | 43 | 57 | | |

Figure 7 - Supply Current

* default setting on SL2101

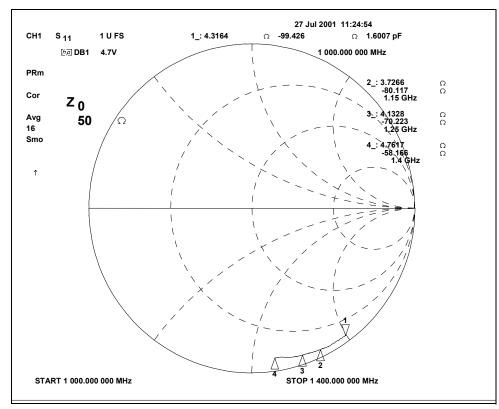


Figure 8 - Typical RF Input Impedance as Broadband Upconverter (Maximum Power Setting)

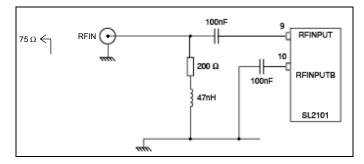


Figure 9 - RF Input Impedance Matching Network as 50 - 860 MHz Upconverter

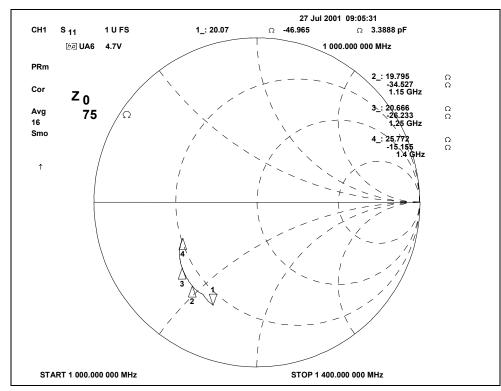


Figure 10 - Typical RF Input Impedance as Narrow Band Downconverter (maximum power setting)

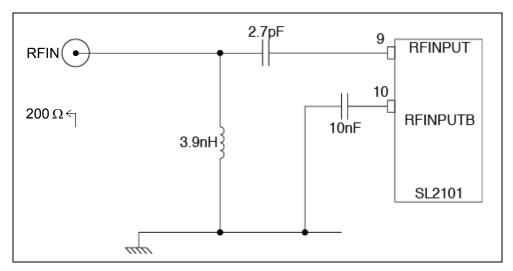


Figure 11 - RF Input Impedance Matching Network as 1.22 GHz Downconverter

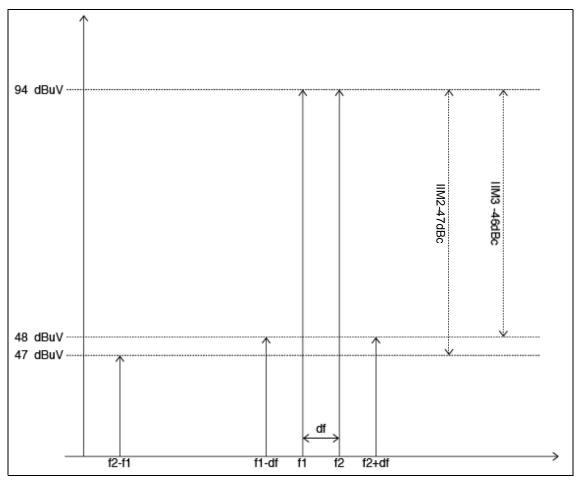


Figure 12 - Two Tone Intermodulation Test Condition Spectrum, Input Referred

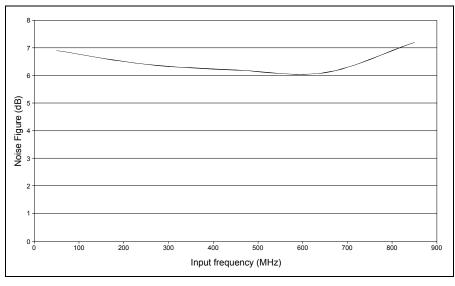


Figure 13 - Input NF, Typical (Maximum Power Setting)

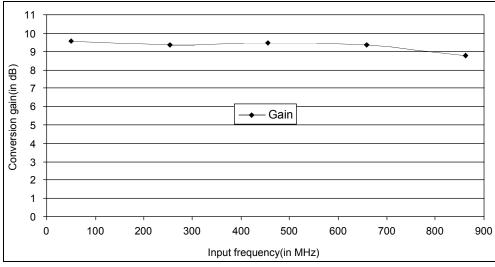


Figure 14 - Conversion Gain as Upconverter (Maximum Power Setting)

| 12 | 11 | 10 | Typ NF (dB) | Gain (dB) | typ CSO* (dBc) | typ CTB* (dBc) | typ IPIP2 (dBμV) | typ IPIP3 (dBμV) |
|----|----|----|----------------|--------------|----------------------|----------------------|------------------------|------------------------|
| 0 | 0 | 0 | 6.8 | 10.1 | -65 | -65 | 144 | 121 |
| 0 | 0 | 1 | 6.0 | 9.1 | -60 | -54 | 141 | 114 |
| 0 | 1 | 0 | 5.8 | 7.6 | -56 | -42 | 132 | 108 |
| 0 | 1 | 1 | 6.5 | 5.4 | -49 | -35 | 129 | 106 |
| 1 | 0 | 0 | 8.7 | 10.4 | -63 | -60 | 146 | 117 |
| 1 | 0 | 1 | 6.2 | 10.0 | -64 | -56 | 142 | 113 |
| 1 | 1 | 0 | 5.9 | 8.3 | -58 | -42 | 133 | 106 |
| 1 | 1 | 1 | 6.4 | 5.8 | -50 | -34 | 126 | 103 |

Figure 15 - Upconverter Gain, NF and Intermodulation with Recommended Load Versus Power Setting

* Measured with 128 channels at +7 dBmV.

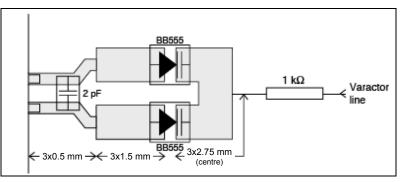


Figure 16 - Upconverter Oscillator Application

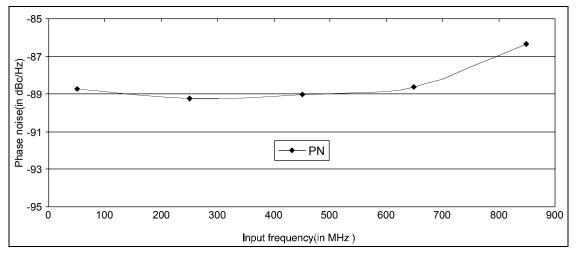


Figure 17 - Oscillator Typical Phase Noise Performance at 10 kHz Offset

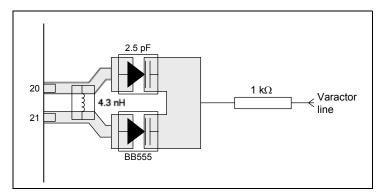


Figure 18 - Downconverter Oscillator Application

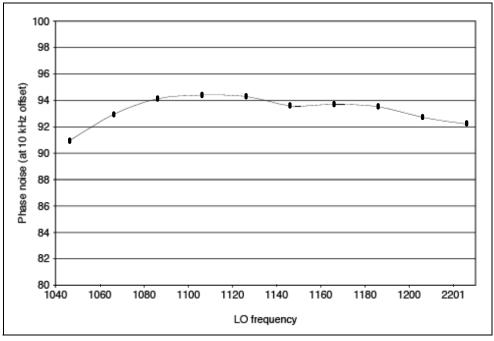


Figure 19 - Typical Phase Noise Performance as Downconverter at 10 kHz Offset

| 12 | 11 | 10 | Typ NF (dB) | Gain (dB) | typ IPIP3 (dBμV) |
|----|----|----|----------------|-----------|---------------------|
| 0 | 0 | 0 | 10.3 | 15.6 | 124 |
| 0 | 0 | 1 | 9.3 | 15.1 | 119 |
| 0 | 1 | 0 | 8.8 | 14.0 | 112 |
| 0 | 1 | 1 | 8.7 | 12.1 | 106 |
| 1 | 0 | 0 | 11.6 | 15.4 | 121.3 |
| 1 | 0 | 1 | 9.0 15.1 | | 119.7 |
| 1 | 1 | 0 | 8.3 | 13.9 | 112.6 |
| 1 | 1 | 1 | 8.0 | 11.9 | 106.3 |

Figure 20 - Downconverter Gain, NF and IP3 with Recommended (Fig. 4) Load Versus Power Setting

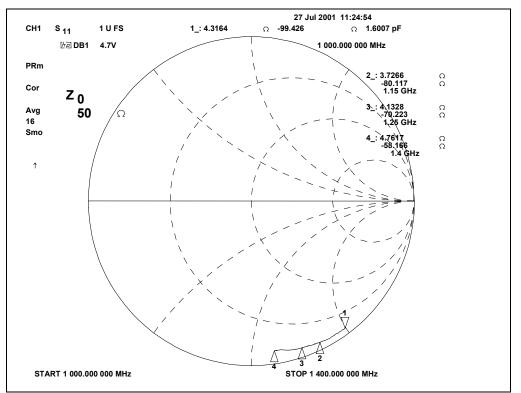
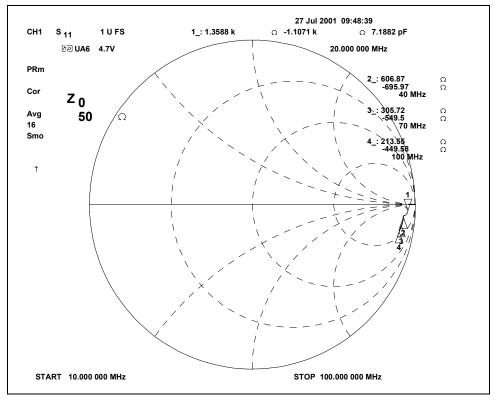


Figure 21 - Typical IF Output Impedance as Upconverter, Single-Ended



| Figure 22 - Typical IF | ^F Output Impedance as | Downconverter, Single-Ended |
|------------------------|----------------------------------|-----------------------------|
|------------------------|----------------------------------|-----------------------------|

| R4 | R3 | R2 | R1 | R0 | Ratio |
|----|----|----|----|----|---------------|
| 0 | 0 | 0 | 0 | 0 | 2 |
| 0 | 0 | 0 | 0 | 1 | 4 |
| 0 | 0 | 0 | 1 | 0 | 8 |
| 0 | 0 | 0 | 1 | 1 | 16 |
| 0 | 0 | 1 | 0 | 0 | 32 |
| 0 | 0 | 1 | 0 | 1 | 64 |
| 0 | 0 | 1 | 1 | 0 | 128 |
| 0 | 0 | 1 | 1 | 1 | 256 |
| 0 | 1 | 0 | 0 | 0 | Illegal state |
| 0 | 1 | 0 | 0 | 1 | 5 |
| 0 | 1 | 0 | 1 | 0 | 10 |
| 0 | 1 | 0 | 1 | 1 | 20 |
| 0 | 1 | 1 | 0 | 0 | 40 |
| 0 | 1 | 1 | 0 | 1 | 80 |
| 0 | 1 | 1 | 1 | 0 | 160 |
| 0 | 1 | 1 | 1 | 1 | 320 |

| R4 | R3 | R2 | R1 | R0 | Ratio |
|----|----|----|----|----|---------------|
| 1 | 0 | 0 | 0 | 0 | Illegal state |
| 1 | 0 | 0 | 0 | 1 | 6 |
| 1 | 0 | 0 | 1 | 0 | 12 |
| 1 | 0 | 0 | 1 | 1 | 24 |
| 1 | 0 | 1 | 0 | 0 | 48 |
| 1 | 0 | 1 | 0 | 1 | 96 |
| 1 | 0 | 1 | 1 | 0 | 192 |
| 1 | 0 | 1 | 1 | 1 | 384 |
| 1 | 1 | 0 | 0 | 0 | Illegal state |
| 1 | 1 | 0 | 0 | 1 | 7 |
| 1 | 1 | 0 | 1 | 0 | 14 |
| 1 | 1 | 0 | 1 | 1 | 28 |
| 1 | 1 | 1 | 0 | 0 | 56 |
| 1 | 1 | 1 | 0 | 1 | 112 |
| 1 | 1 | 1 | 1 | 0 | 224 |
| 1 | 1 | 1 | 1 | 1 | 448 |

| Figure | 23 - | Reference | Division | Ratios |
|--------|------|-----------|----------|--------|
|--------|------|-----------|----------|--------|

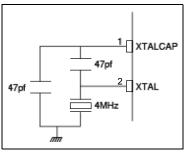
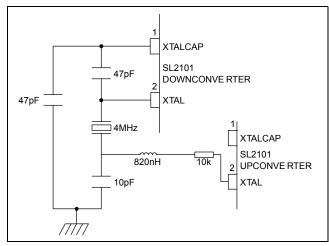


Figure 24 - Standard Application





| T2 | T1 | Т0 | Test Mode Description |
|----|----|----|--|
| 0 | 0 | 0 | Normal operation |
| 0 | 0 | 1 | Charge pump sink * Status byte FL set to logic '0' |
| 0 | 1 | 0 | Charge pump source * Status byte FL set to logic '0' |
| 0 | 1 | 1 | Charge pump disabled * Status byte FL set to logic '1' |
| 1 | 0 | 0 | Normal operation and Port P0 = Fpd/2 |
| 1 | 0 | 1 | Charge pump sink * Status byte FL set to logic '0' Port P0 = Fcomp |
| 1 | 1 | 0 | Charge pump source * Status byte FL set to logic '0' Port P0 = F _{comp} |
| 1 | 1 | 1 | Charge pump disabled * Status byte FL set to logic '1' Port P0 = F _{comp} |

Figure 26 - Test Modes

* clocks need to be present on crystal and local oscillator to enable charge pump test modes and to toggle status byte bit FL.

| RE | BUFREF output |
|----|--------------------------|
| 0 | disabled, high impedance |
| 1 | enabled |

Note: The BUFREF output is only available on the SSOP package

Figure 27 - Buffered Crystal Reference Output Select

| | MSB | | | | | | | LSB | | |
|-------------------------|----------------|-----------------|-----------------|-----------------|-----------------|-----------------|----------------|----------------|---|--------|
| Address | 1 | 1 | 0 | 0 | 0 | MA1 | MA0 | 0 | А | Byte 1 |
| Programmable divider | 0 | 2 ¹⁴ | 2 ¹³ | 2 ¹² | 2 ¹¹ | 2 ¹⁰ | 2 ⁹ | 2 ⁸ | A | Byte 2 |
| Programmable divider | 2 ⁷ | 2 ⁶ | 2 ⁵ | 2 ⁴ | 2 ³ | 2 ² | 2 ¹ | 2 ⁰ | A | Byte 3 |
| Control data | 1 | C1 | C0 | R4 | R3 | R2 | R1 | R0 | А | Byte 4 |
| Control data | T2 | T1 | Т0 | 12 | 11 | 10 | RE | P0 | А | Byte 5 |

Table 1 - Write Data Format (MSB is transmitted first)

| M | 9 | R |
|----|---|---|
| IV | 9 | |

LSB

| Address | 1 | 1 | 0 | 0 | 0 | MA1 | MA0 | 1 | А | Byte 1 |
|-------------------------|-----|----|---|---|---|-----|-----|---|---|--------|
| Programmable divider | POR | FL | 0 | 0 | 0 | 0 | 0 | 0 | A | Byte 2 |

| A MA1,MA0 | : | Acknowledge bit Variable address bits (see Table 3) |
|---------------------------------|---|---|
| 2 ¹⁴ -2 ⁰ | : | Programmable division ratio control bits |
| 12-10 | : | Ina/mixer power select (see Figure 7) |
| C1-C0 | : | Charge pump current select (see Figure 29) |
| R4-R0 | : | Reference division ratio select (see Figure 23) |
| T2-T0 | : | Test mode control bits (see Figure 26) |
| RE | : | Buffered crystal reference output enable (see Figure 27 |
| P0 | : | P0 port output state |
| POR | : | Power on reset indicator |
| FL | : | Phase lock flag |

| MA0 | Address input voltage level | | | | | |
|-----|-----------------------------|--|--|--|--|--|
| 0 | 0-0.1Vcc | | | | | |
| 1 | Open circuit | | | | | |
| 0 | 0.4Vcc – 0.6 Vcc # | | | | | |
| 1 | 0.9 Vcc - Vcc | | | | | |
| - | MA0 0 1 0 1 | | | | | |

Table 3 - Address Selection

Figure 28 - Read/Write Data Formats

| C1 | CO | Current in mA | | | | | | |
|----|----|---------------|--------|--------|--|--|--|--|
| | 0 | Min. | Тур. | Max. | | | | |
| 0 | 0 | +-98 | +-130 | +-162 | | | | |
| 0 | 1 | +-210 | +-280 | +-350 | | | | |
| 1 | 0 | +-450 | +-600 | +-750 | | | | |
| 1 | 1 | +-975 | +-1300 | +-1625 | | | | |

Figure 29 - Charge Pump Current

Electrical Characteristics - Test conditions (unless otherwise stated). $T_{amb} = -40^{\circ}$ to 85° C, Vee= 0V, Vcc=5 V+-5%. These characteristics are guaranteed by either production test or design. They apply within the specified ambient temperature and supply voltage at maximum power setting unless otherwise stated.

| Characteristic | Pin | Min. | Тур. | Max. | Units | Conditions |
|--|------------------------|------|------|------|-------|--|
| Supply current | 6, 12,17, 19, 22 | | 90 | 120 | mA | IF outputs will be connected to Vcc through the differential load as in Figures 4, 5 & 6. See Figure 7 for programmable settings. |
| Input frequency range | 9, 10 | 50 | | 1400 | MHz | Operating condition only. |
| Output frequency range | 14, 15 | 30 | | 1400 | MHz | Operating condition only. |
| Composite peak input signal | 9, 10 | | 97 | | dBμV | Operating condition only. |
| All synthesizer related spurs on IF Output | 14, 15 | | | -60 | dBc | Within channel bandwidth of 8 MHz and with input power of 60 dBμV. |
| Upconverter application | | | | | | |
| Input frequency range | 9, 10 | 50 | | 860 | MHz | |
| Input impedance | | | 75 | | Ω | See Figure 8. |
| Input return loss | | 6 | | | dB | With input matching network as in Figure 9. |
| Input Noise Figure | | | | 9.5 | dB | Tamb=27°C, see Figure 13, with input matching network as in Figure 9. See Figure 15 for programmable settings. |
| Conversion gain | | | 9 | | dB | Differential voltage gain to 200 Ω load on output of SAWF as in Figure 4, see Figure 14. See Figure 15 for programmable settings. |

| Characteristic | Pin | Min. | Тур. | Max. | Units | Conditions |
|--|--------|------|-------------|------|------------------|--|
| Gain variation across operation range | | -1 | | +1 | dB | 50-860 MHz |
| Gain variation within channel | | | | 0.5 | dB | Channel bandwidth 8 MHz within operating frequency range. |
| Through gain | | | | -20 | dB | 45-1400 MHz |
| CSO | | | -65 | | dBc | Measured with 128 channels at 62 dB μ V. See Figure 15 for programmable settings. |
| СТВ | | | -68 | | dBc | Measured with 128 channels at 62 dB μ V. See Figure 15 for programmable settings. |
| IPIP2 _{2T} | | 141 | | | dBuV | See Note 2. See Figure 15 for programmable settings. |
| IPIP3 _{2T} | | 117 | | | dBuV | See Note 2. See Figure 15 for programmable settings. |
| IPIM2 _{2T} | | | | -47 | dBc | See Note 2. See Figure 12. |
| IPIM3 _{2T} | | | | -46 | dBc | See Note 2. See Figure 12. |
| LO operating range | | 1 | | 2.3 | GHz | Maximum tuning range 0.9 GHz determined by application. |
| LO phase noise, SSB @ 10 kHz offset @ 100 kHz offset | | | -86 -106 | | dBc/Hz dBc/Hz | Application as in Figure 16. See Figure 17. |
| LO phase noise floor | | | | -136 | dBc/Hz | Application as in Figure 16. |
| IF output frequency range | 14, 15 | 1 | | 1.4 | GHz | |
| IF output impedance | | | | | | See Figure 21. |
| Downconverter application | | | | | | |
| Input frequency range | 9, 10 | 1000 | | 1400 | MHz | |
| Input impedance | | | 75 | | Ω | See Figure 10. |
| Input return loss | | 12 | | | dB | With input matching network as in Figure 11. |
| Input Noise Figure | | | | 14 | dB | Tamb=27 [°] C, with input matching network as in Figure 11. See Figure 20 for programmable settings. |

| Characteristic | Pin | Min. | Тур. | Max. | Units | Conditions |
|--|--------|------|-------------|------------|------------------|---|
| Conversion gain | | | 12 | | dB | Differential voltage gain to 50 Ω load on output of impedance transformer as in Figure 6. See Figure 20 for programmable settings. |
| Gain variation within channel | | | | 0.5 | dB | Channel bandwidth 8 MHz within operating frequency range. |
| Through gain | | | | -20 | dB | 45-1400 MHz |
| IPIP3 _{2T} | | 117 | | | dBμV | See Note 2. |
| IPIM3 _{2T} | | | | -46 | dBc | See Note 2. See Figure 12. |
| LO operating range | | 1 | | 2.3 | GHz | Maximum tuning range determined by application, see Note 4. |
| LO phase noise, SSB @ 10 kHz offset @ 100 kHz offset | | | -92 -112 | | dBc/Hz dBc/Hz | Application as in Figure 18. See Figure 19. |
| LO phase noise floor | | | | -136 | dBc/Hz | Application as in Figure 18. |
| IF output frequency range | 14, 15 | | | 100 | MHz | |
| IF output impedance | | | | | | See Figure 22. |
| Synthesizer | | | | | | |
| SDA, SCL | 3, 4 | | | | | |
| Input high voltage | | 3 | | 5.5 | V | I ² C 'Fast mode' compliant |
| Input low voltage | | 0 | | 1.5 | V | |
| Input high current | | | | 10 | μA | Input voltage = Vcc |
| Input low current | | -10 | | | μA | Input voltage = Vee |
| Leakage current | | | | 10 | μA | Vcc=Vee |
| Hysterysis | | | 0.4 | | | |
| SDA output voltage | 3 | | | 0.4 0.6 | V V | Isink = 3 mA Isink = 6 mA |
| SCL clock rate | 4 | | | 400 | kHz | |
| Charge pump output current | 28 | | | | | See Figure 29. Vpin = 2 V |
| Charge pump output leakage | 28 | | +-3 | +-10 | nA | Vpin = 2 V |

| Characteristic | Pin | Min. | Тур. | Max. | Units | Conditions |
|--|-----|------|------|-----------|----------|---|
| Charge pump drive output current | 27 | 0.5 | | | mA | Vpin = 0.7 V |
| Crystal frequency | 1,2 | 2 | | 20 | MHz | See Figure24 and Figure 25 for application. |
| Recommended crystal series resistance | | 10 | | 200 | Ω | 4 MHz parallel resonant crystal |
| External reference input frequency | 2 | 2 | | 20 | MHz | Sinewave coupled through 10 nF blocking capacitor |
| External reference drive level | 2 | 0.2 | | 0.5 | Vpp | Compatible with BUFREF output. (SSOP package only) |
| Phase detector comparison frequency | | | | 4 | MHz | |
| Equivalent phase noise at phase detector | | | | | | SSB, within loop bandwidth |
| | | | -148 | | dBc/Hz | F _{comp} = 1 MHz |
| | | | -152 | | dBc/Hz | F _{comp} = 250 kHz |
| | | | -158 | | dBc/Hz | F _{comp} = 62.5 kHz |
| Local oscillator programmable divider division ratio | | 240 | | 32767 | | |
| Reference division ratio | | | | | | See Figure 23. |
| Output port sink current leakage current | 26 | 2 | | 10 | mA μA | See Note 3. Vport = 0.7 V Vport =Vcc |
| BUFREF output output amplitude | 5 | | 0.35 | | Vpp | AC coupled. Note 5. Enabled by bit RE=1 and default |
| output impedance | | | 250 | | Ω | state on power-up. BUFREF output only available on SSOP package |
| Address select Input high current Input low current | | | | 1 -0.5 | mA mA | See Figure 28, Table 3 Vin=Vcc Vin=Vee |

Note 1: All power levels are referred to 75 Ω and 0 dBm = 109 dB μV

Note 2: Any two tones within RF operating range at 94 dB μ V beating within band, with output load as in Figure 4

Note 3: Port powers up in high impedance state

Note 4: To maximise phase noise the tuning range should be minimised and Q of resonator maximised. The application as in Figure 18 has a tuning range of 200 MHz.

Note 5: If the BUFREF output is not used it should be left open circuit or connected to Vccd and disabled by setting RE = '0'.

| Characteristic | Pin | Min. | Max. | Units | Conditions |
|--|-------------------------|------|---------|-------|----------------------------------|
| Supply voltage, V _{cc} | 6, 12, 17, 19, 22 | -0.3 | 6 | V | |
| RF input voltage | 9, 10 | | 117 | dBuV | Differential, AC coupled inputs |
| All I/O port DC offsets | | -0.3 | Vcc+0.3 | V | |
| SDA, SCL DC offsets | 3, 4 | -0.3 | 6 | V | Vcc = Vee to 5.25 V |
| Storage temperature | | -55 | 150 | °C | |
| Junction temperature | | | 125 | °C | Power applied. |
| Package thermal resistance, chip to case (SSOP) | | | 20 | °C/W | |
| Package thermal resistance, chip to ambient (SSOP) | | | 85 | °C/W | |
| Power consumption at 5.25 V | | | 630 | mW | Maximum power setting. |
| ESD protection (pins 3-28) | | 1 | | kV | Mil-std 883B method 3015 cat1 |
| ESD protections (pins 1, 2) | | 0.75 | | kV | |

Absolute Maximum Ratings - All voltages are referred to Vee at 0 V (pins 7, 8, 11, 13, 16, 18, 23, 25).

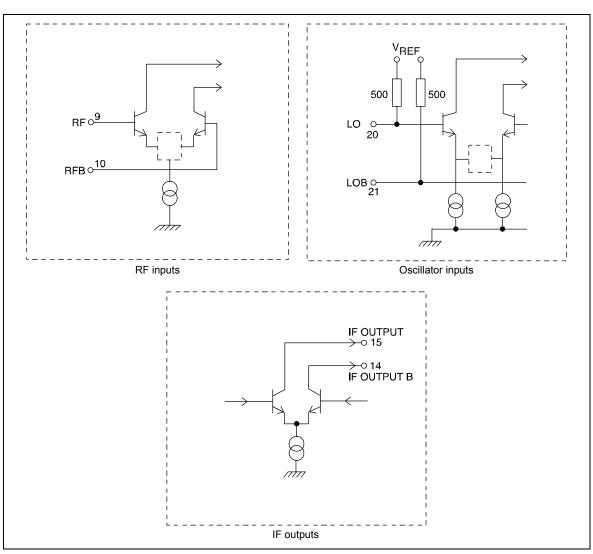


Figure 30 - Input and Output Interface Circuits (RF section)

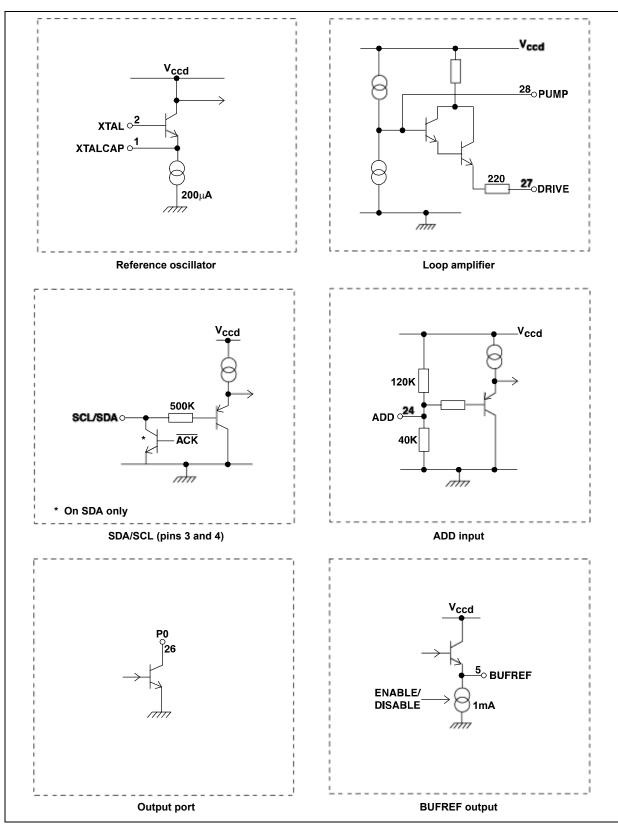
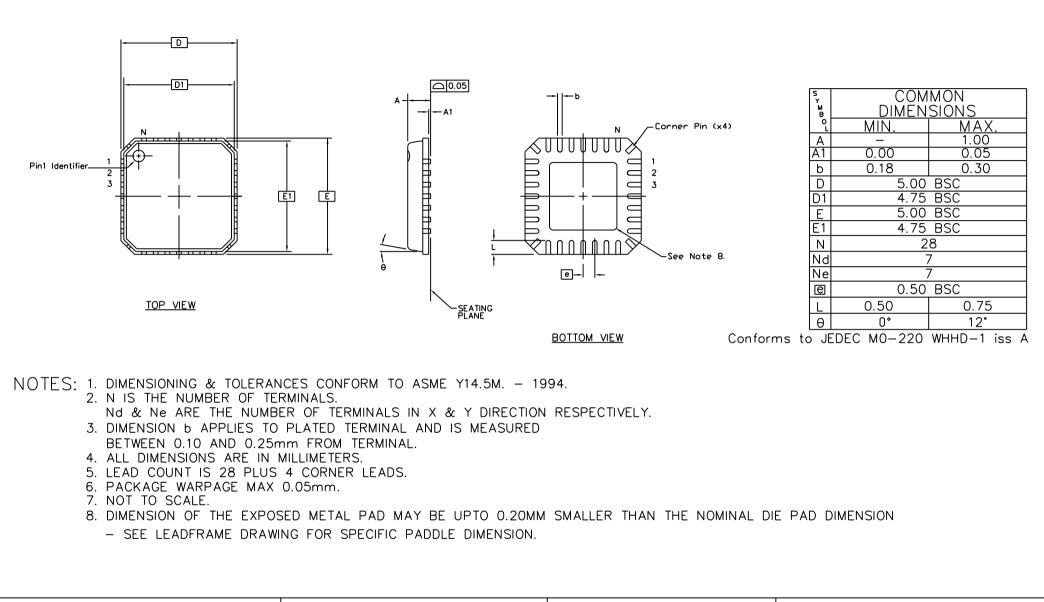
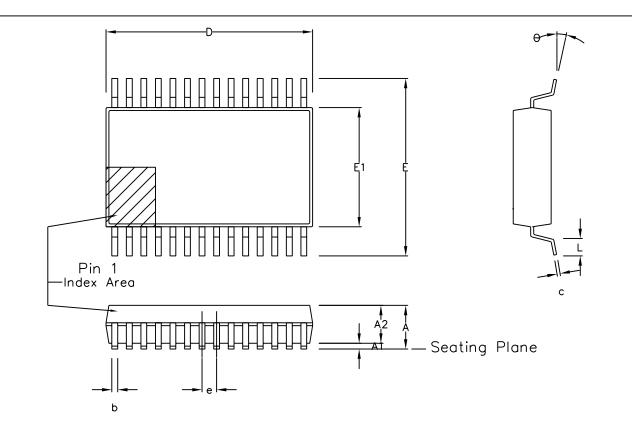


Figure 31 - Input and Output Interface Circuits (PLL section)



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|-----------|--------------|-----------------|--------------|---------|---|---------------------------------|------------------------|-----------------------------|
| ISSUE | 2 | 3 | 4 | 5 | | | Previous package codes | Package Outline for Stamped |
| ACN | 208382 | 208538 | 212490 | CDCA | | ZARLINK SEMICONDUCTOR | LH | 28 (+4) Lead QFN (5x5mm) |
| DATE | 17Feb00 | 16Mar00 | 8Apr02 | 17Dec03 | | SEMICONDUCTOR | | |
| APPRD. | | | | | | | | GPD00632 |



| Symbol | | ol Dimer millimet | | | Altern. Dimensions in inches | | | | |
|------------------------------------|-----------------|----------------------|-------|--|---------------------------------|---------|--------|--|--|
| | MIN Nominal MAX | | | | MIN | Nominal | MAX | | |
| Α | 1.70 | | 2.00 | | 0.067 | | 0.079 | | |
| A1 | 0.05 | | 0.20 | | 0.002 | | 0.008 | | |
| A2 | 1.65 | | 1.85 | | 0.065 | | 0.073 | | |
| D | 9.90 | | 10.50 | | 0.390 | | 0.413 | | |
| E | 7.40 | | 8.20 | | 0.291 | | 0.323 | | |
| E1 | 5.00 | | 5.60 | | 0.197 | | 0.220 | | |
| L | 0.55 | | 0.95 | | 0.022 | | 0.037 | | |
| е | 0.65 BSC. | | | | 0.026 BSC. | | | | |
| b | 0.22 | | 0.38 | | 0.009 | | 0.015 | | |
| С | 0.09 | | 0.25 | | 0.004 | | 0.010 | | |
| Θ | 0° | | 8' | | 0° | | ° 8 | | |
| | Pin features | | | | | | | | |
| Ν | 28 | | | | | | | | |
| Conforms to JEDEC MO-150 AH Iss. B | | | | | | | | | |

This drawing supersedes: -418/ED/51481/004 (Swindon/Plymouth)

Notes:

- 1. A visual index feature, e.g. a dot, must be located within the cross-hatched area.
- 2. Controlling dimension are in millimeters.
- 3. Dimensions D and E1 do not include mould flash or protusion. Mould flash or protusion shall not exceed
- 0.20 mm per side. D and E1 are maximum plastic body size dimensions including mould mismatch.
 4. Dimension b does not include dambar protusion/intrusion. Allowable dambar protusion shall be 0.13 mm total in excess of b dimension. Dambar intrusion shall not reduce dimension b by more than 0.07 mm.

| © Zarlink Semiconductor 2002 All rights reserved. | | | | - | | Package Code |
|---|---------|---------|--------|---|------------------------|--|
| ISSUE | 1 | 2 | 3 | | Previous package codes | Package Outline for 28 lead SSOP (5.3mm Body Width) |
| ACN | 201935 | 205232 | 212478 | | | |
| DATE | 27Feb97 | 25Sep98 | 3Apr02 | | | |
| APPRD. | | | | | | GPD00296 |



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